



$V_{CE}$	<b>1200</b>	<b>V</b>
$I_C$	<b>15</b>	<b>A</b>
$V_{CE(SAT)} I_C=15A$	<b>1.85</b>	<b>V</b>

- AC and DC servo drive amplifier
- Uninterruptible power supply

Maximum junction temperature  $\theta$

## Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-Emitter Breakdown Voltage	$V_{CE}$	1200	V
DC Collector Current, limited by $T_{jmax}$ $T_C=25^\circ C$ $T_C=100^\circ C$	$I_C$	30 15	A
Diode Forward Current, limited by $T_{jmax}$ $T_C=25^\circ C$ $T_C=100^\circ C$	$I_F$	30 15	A
Continuous Gate-Emitter Voltage	$V_{GE}$	( ± 20 M , (	V

Transient Gate-Emitter Voltage

V E

$V_{GE}=15V,$ tp limited by $T_{jmax}$	$I_{CM}$	60	A
Diode Pulsed Current, tp limited by $T_{jmax}$	$I_{Fpuls}$	60	A

Short Circuit Withstand Time,

$V_{GE}=15V, V_{CC}=900V \quad V_{CEM} \quad 1200V$

$T_{sc}$

Operating Junction Temperature	$T_j$	-40...+175	°C
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## Electrical Characteristics of the IGBT $T_j = 25$ unless otherwise specified

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Collector-Emitter Breakdown Voltage	$BV_{CES}$	$V_{GE}=0V, I_C=250\mu A$	1200		-	V
Gate Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=0.5mA$	5.1	5.8	6.4	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V, I_C=15A$ $T_j=25^\circ C,$ $T_j=125^\circ C$ $T_j=150^\circ C$		1.85 2.20 2.30	2.35	V
Zero Gate Voltage Collector Current	$I_{CES}$	$V_{CE}=1200V, V_{GE}=0V$ $T_j=25^\circ C,$ $T_j=150^\circ C$			0.25 5.00	mA
Gate-Emitter Leakage Current	$I_{GES}$	$V_{CE}=0V, V_{GE}=\pm 20V$			100	nA

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
<b>Dynamic</b>						
Input Capacitance	$C_{ies}$	$V_{CE}=25V, V_{GE}=0V,$ $f=1MHz$	-	1.2	-	nF
Reverse Transfer Capacitance	$C_{res}$		-	0.04	-	
Gate Charge	$Q_G$	$V_{CC}=960V, I_C=15A,$ $V_{GE}=15V$	-	0.14	-	uC
Short Circuit Collector Current	$I_{SC}$	$V_{GE}=15V, t_{sc} 10\mu s,$ $V_{CC}=900V, T_j 150^\circ C$	-	60	-	A

## Electrical Characteristics of the Diode $T_j=25$ unless otherwise specified

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Diode Forward Voltage	$V_F$	$I_F=15A$ $T_j=25^\circ C$ , $T_j=125^\circ C$ $T_j=150^\circ C$		2.00 1.80 1.70	2.40	V

## Switching Characteristic, Inductive Load

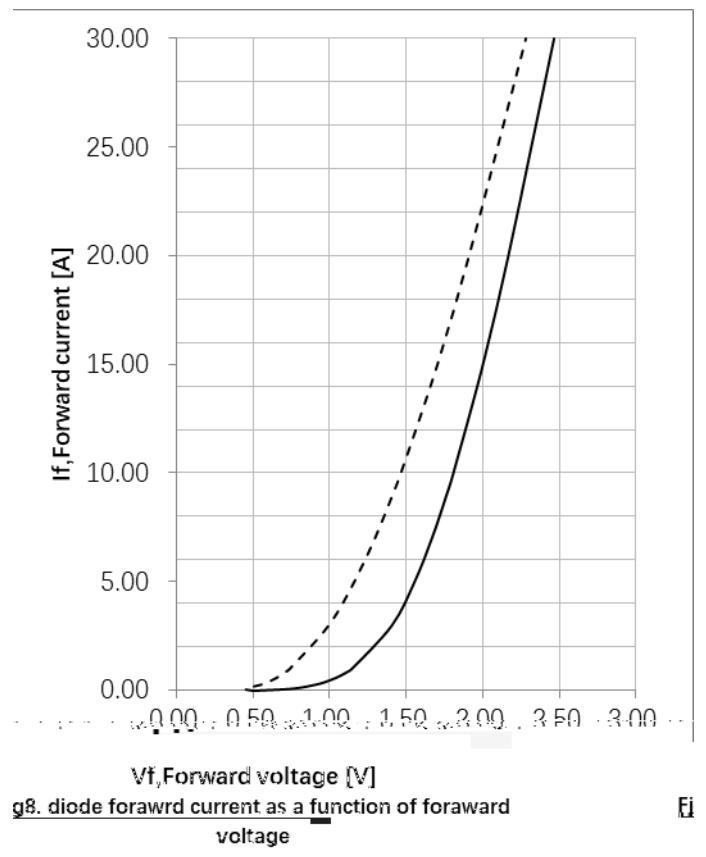
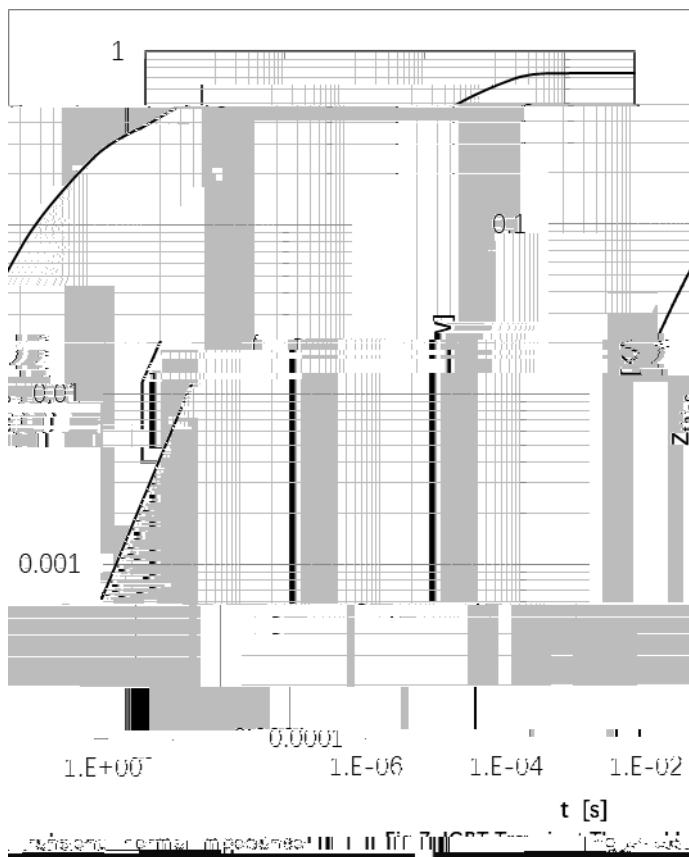
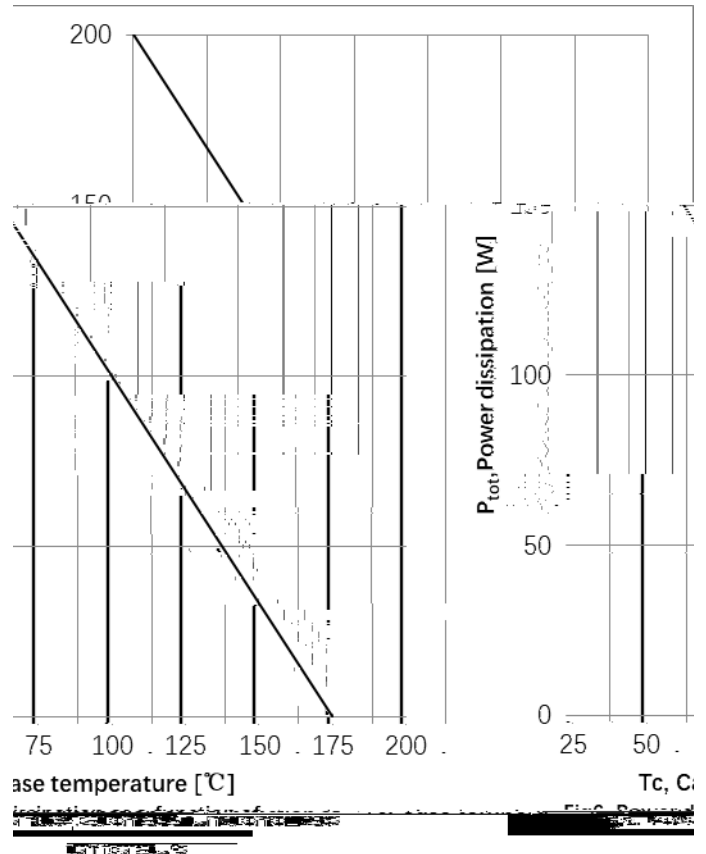
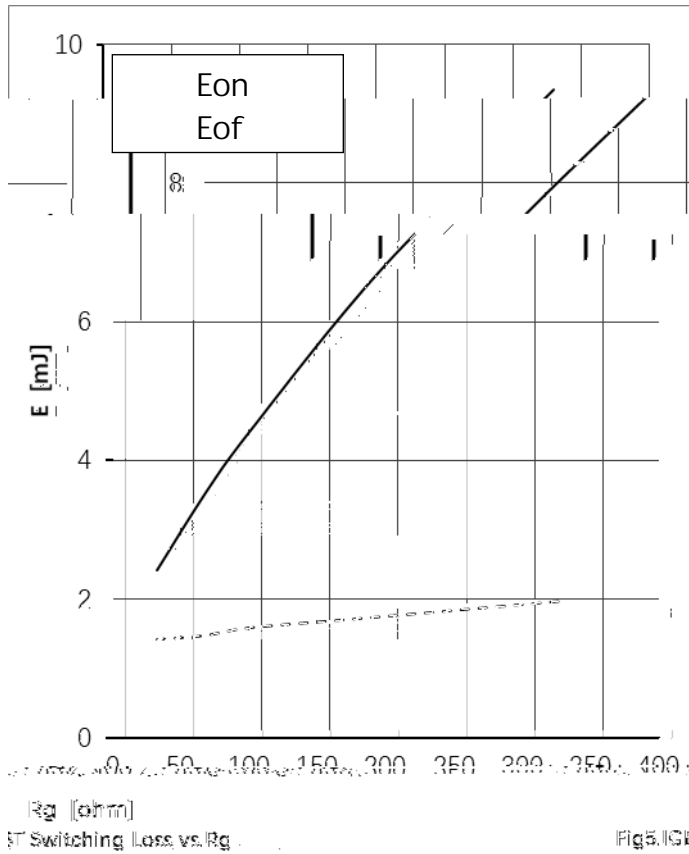
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
<b>Dynamic , at <math>T_j=25</math></b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{CC}=600V, I_C=15A,$ $V_{GE}=-15V\sim 15V,$ $R_g=33$	-	45	-	ns
Rise Time	$t_r$		-	52	-	ns
Turn-on Energy	$E_{on}$		-	1.5	-	mJ
Turn-off Delay Time	$t_{d(off)}$		-	128	-	ns
Fall Time	$t_f$		-	186	-	ns
Turn-off Energy	$E_{off}$		-	0.9	-	mJ
<b>Dynamic , at <math>T_j=125</math></b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{CC}=600V, I_C=15A,$ $V_{GE}=-15V\sim 15V,$ $R_g=33$	-	50	-	ns
Rise Time	$t_r$		-	55	-	ns
Turn-on Energy	$E_{on}$		-	2.2	-	mJ
Turn-off Delay Time	$t_{d(off)}$		-	160	-	ns
Fall Time	$t_f$		-	135	-	ns
Turn-off Energy	$E_{off}$		-	1.3	-	mJ
<b>Dynamic , at <math>T_j=150</math></b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{CC}=600V, I_C=15A,$ $V_{GE}=-15V\sim 15V,$ $R_g=33$	-	52	-	ns
Rise Time	$t_r$		-	58	-	ns
Turn-on Energy	$E_{on}$		-	2.4	-	mJ
Turn-off Delay Time	$t_{d(off)}$		-	170	-	ns
Fall Time	$t_f$		-	138	-	ns
Turn-off Energy	$E_{off}$		-	1.45	-	mJ

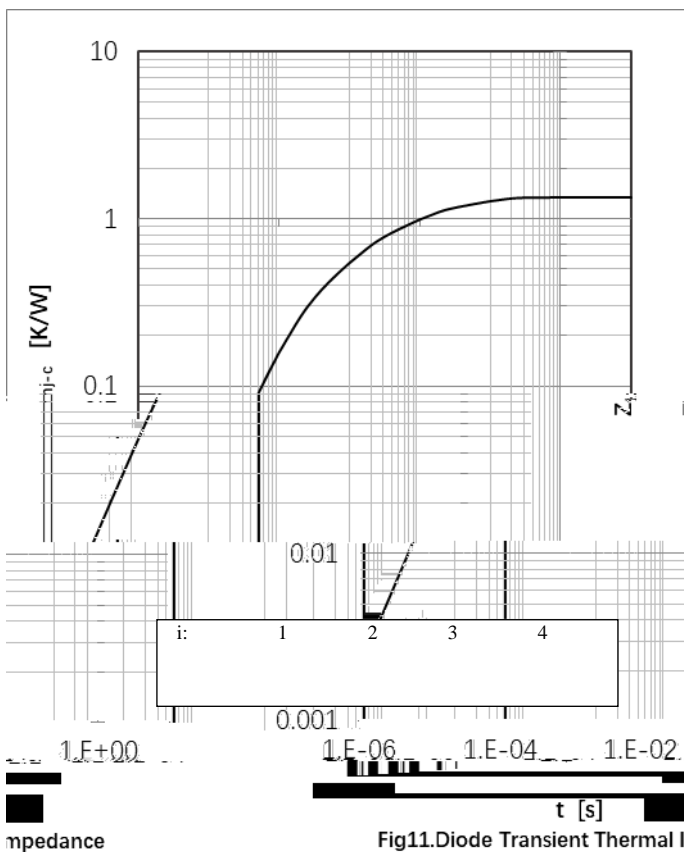
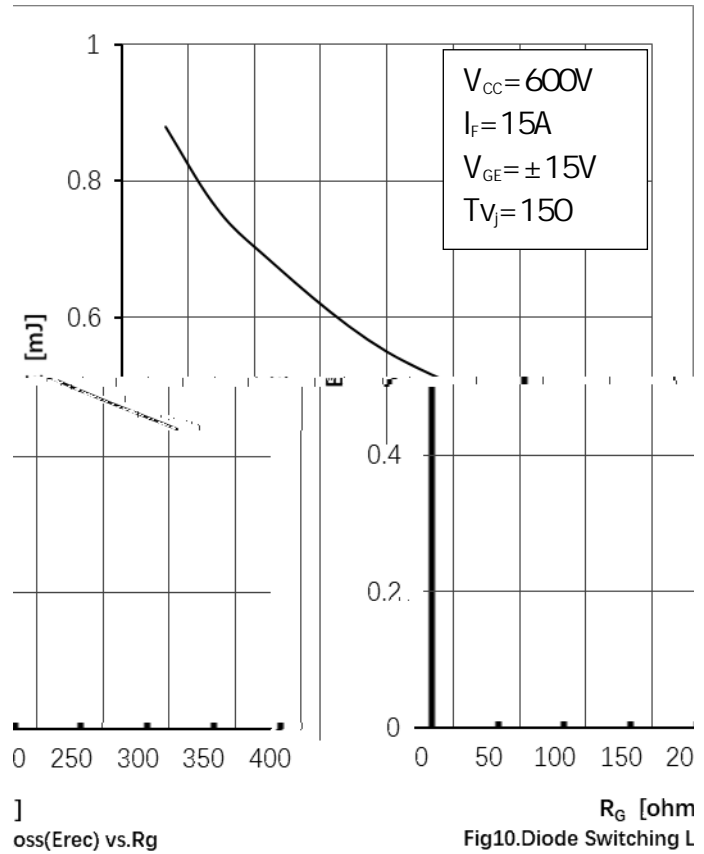
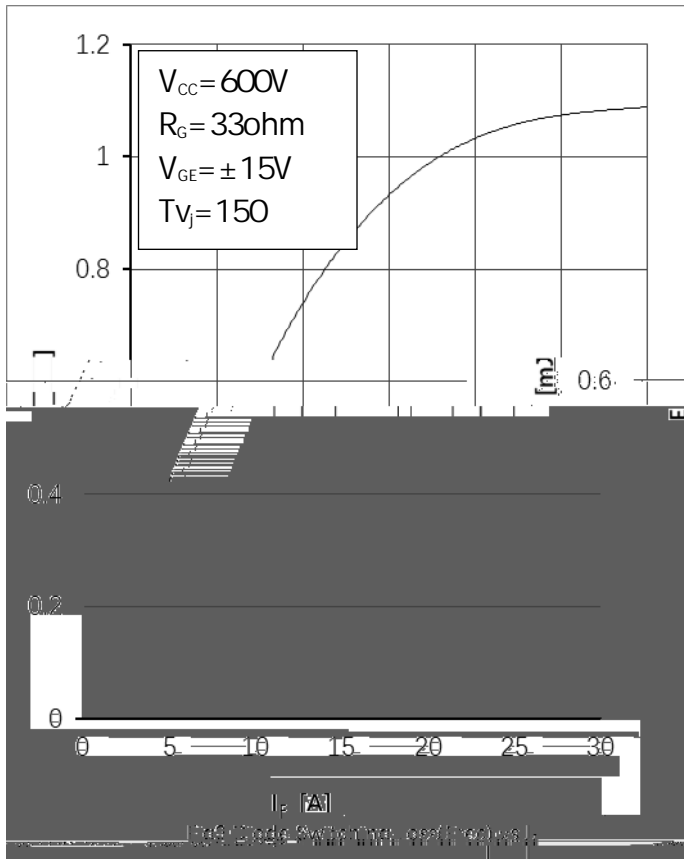


# DGW15N120CTL



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- Circuit Diagram